NPN Epitaxial Planar Silicon Transistor



2SC4364

VHF, UHF/MIX. OSC. Low-Voltage High-Frequency Amplifier Applications

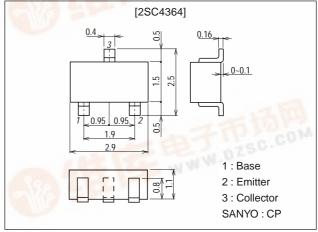
Features

- · Low-voltage operation
 - : $f_T=3.0GHz$ typ ($V_{CE}=3V$)
 - : MAG=11dB typ (V_{CE} =3V, I_{C} =3mA)
 - : NF=3.0dB typ (V_{CE} =3V, I_{C} =3mA)

Package Dimensions

unit:mm

2018B



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		25	V
Collector-to-Emitter Voltage	VCEO		15	V
Emitter-to-Base Voltage	V _{EBO}	pall	3	V
Collector Current	IC		30	mA
Collector Dissipation	PC	and Color to	250	mW
Junction Temperature	Tj	ATT THE V	150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
1 diameter	Cyllibol			typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =15V, I _E =0			1.0	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =2V, I _C =0			1.0	μΑ
DC Current Gain	h _{FE}	V _{CE} =3V, I _C =3mA	40*		200*	77
Gain-Bandwidth Product	fT	V _{CE} =3V, I _C =3mA		3.0		GHz
Output Capacitance	C _{ob}	V _{CB} =3V, f=1MHz	40	0.75	1.3	pF
Reverse Transfer Capacitance	C _{re}	V _{CB} =3V, f=1MHz	-	0.7	, D. C.	pF

* : The 2SC4364 is classified by 3mA h_{FE} as follows : 40

Classified by 3mA h_{FE} as follows: 40 2 80 60 3 120 100 4 200 T

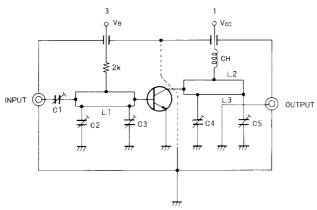
(Note) Marking: OT h_{FE} rank: 2, 3, 4

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TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

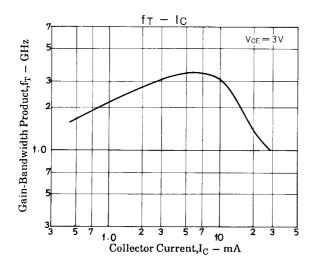
Parameter	Symbol	Conditions		Ratings		
i arameter	Gymbol	Conditions	min	typ	max	Unit
Forward Transfer Gain	S21e ²	V _{CE} =3V, I _C =3mA, f=0.9GHz		7		dB
Maximum Available Power Gain	MAG	V _{CE} =3V, I _C =3mA, f=0.9GHz		11		dB
Noise Figure	NF	V _{CE} =3V, I _C =3mA, f=0.9GHz		3.0	5.0	dB

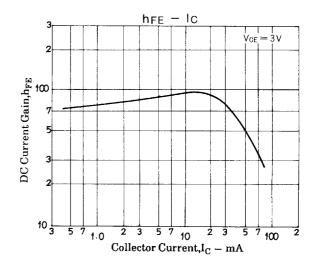
NF Test Circuit

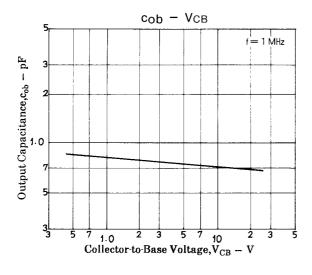


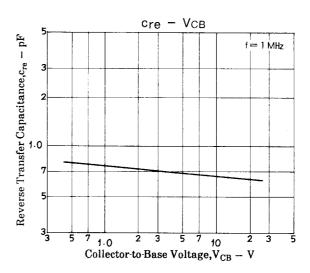
	900MHz
C1	~5pF
C2	~10pF
C3	~10pF
C4	~10pF
C5	~10pF
L1	W ≈ 1.5mm, I ≈ 25mm Strip line
L2	W ≈ 4mm, I ≈ 25mm Strip line
L3	0.5φ, I ≈ 40mm
СН	2t+bead core

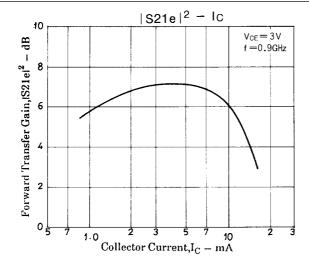
Unit (resistance : Ω)

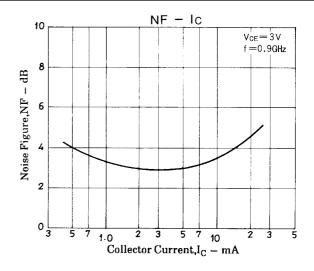


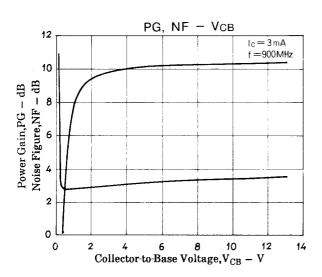


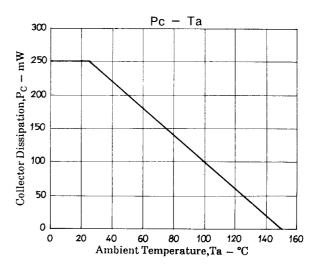






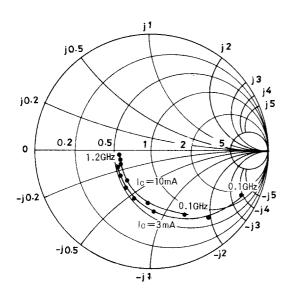


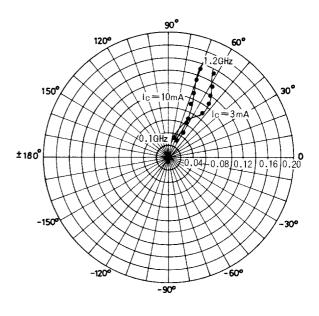




S parameter

S11e: Vce= 3 V f=100MHz, 200 to1200MHz(200MHz step) S12e: V_{CE}= 3 V f=100MHz, 200 to 1200MHz(200MHz step)



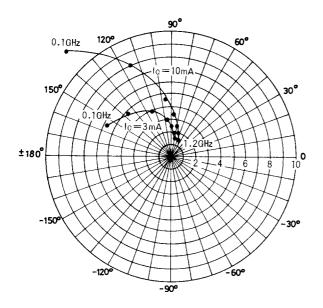


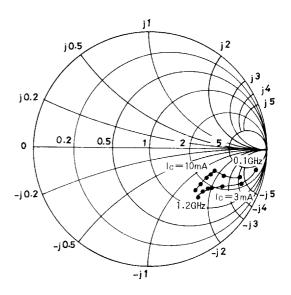
S21e: V_{CE}= 3 V

f=100MHz, 200 to 1200MHz (200MHz step)

S22e:VCE=10V

f=100MHz, 200 to 1200MHz (200MHz step)





S parameter (Common emitter)

 V_{CE} =3V, I_{C} =3mA, Z_{O} =50 Ω

Freq (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
100	0.874	-25.4	5.638	154.7	0.036	73.4	0.931	-12.4
200	0.758	-46.8	4.895	137.3	0.061	62.3	0.842	-19.9
400	0.555	-85.9	3.925	112.5	0.088	53.7	0.696	-26.7
600	0.437	-110.1	3.004	97.1	0.105	53.2	0.631	-30.3
800	0.377	-127.8	2.387	86.7	0.119	56.2	0.596	-32.9
900	0.361	-135.3	2.201	82.7	0.128	57.3	0.594	-34.4
1000	0.353	-141.9	2.014	79.1	0.135	56.5	0.586	-36.1
1200	0.340	-151.4	1.763	72.7	0.153	60.6	0.581	-40.1

 $V_{CE}=3V, I_{C}=10mA, Z_{O}=50\Omega$

Freq (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
100	0.632	-59.2	11.508	135.2	0.031	63.9	0.811	-18.4
200	0.467	-92.6	7.923	115.1	0.045	58.7	0.677	-21.8
400	0.352	-129.6	4.570	95.5	0.067	61.8	0.584	-22.7
600	0.317	-147.2	3.190	85.3	0.089	65.4	0.561	-25.8
800	0.307	-157.8	2.432	78.1	0.109	68.6	0.548	-29.2
900	0.308	-162.6	2.217	75.1	0.122	69.1	0.551	-31.2
1000	0.314	-166.9	2.023	72.2	0.133	70.1	0.547	-33.3
1200	0.318	-172.2	1.756	67.0	0.156	70.1	0.549	-38.1

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